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CLAIMS

What is claimed is

- 1 1. A method of forming an electrical interconnection
- 2 between a first electrical device and a second electrical
- 3 device comprising the steps of:
- 4 providing contacts in an uncompressed state;
- deforming the contacts to a compressed state;
- 6 positioning the contacts in a device adapted to hold
- 7 the contacts between the first and second electrical
- 8 devices; and
- 9 activating the contacts to substantially expand the
- 10 contacts to the uncompressed state, wherein each
- 11 contact expands to substantially its uncompressed
- 12 state for establishing the electrical
- interconnection between the first and second
- 14 electrical devices.
- 15 2. A method in accordance with Claim 1 wherein the
- 16 device for positioning the contacts comprises a land grid
- 17 array.
- 18 3. A method in accordance with Claim 1 wherein each
- 19 contact is composed of a shape memory material.

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- 1 4. A method in accordance with Claim 3 further
- 2 including the shape memory material being superelastic
- 3 material.
- 4 5. A method in accordance with Claim 3 wherein the
- 5 shape memory material is a nickel titanium alloy.
- 6 6. A method of forming an electrical interconnection
- 7 between a first electrical device and a second electrical
- 8 device comprising the steps of:
- 9 providing contacts in an uncompressed state and
- 10 composed of a shape memory material;
- 11 positioning the contacts in a device adapted to hold
- the contacts between the first and second electrical
- 13 devices; and
- 14 positioning the device with the contacts therein for
- 15 establishing electrical interconnection between the
- 16 first electrical device and the second electrical
- 17 device.
- 18 7. A method in accordance with Claim 6 wherein the
- 19 device for positioning the contacts comprises a land grid
- 20 array.
- 21 8. A method in accordance with Claim 7 further
- 22 including a step of providing the contact being made of a
- 23 shape memory material having superelastic properties.

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- 1 9. A method in accordance with Claim 6 wherein in the
- shape memory material is a nickel titanium alloy.
- 3 10. A method of forming an electrical connection between
- a first electrical device and a second electrical device
- 5 comprising the steps of:
- 6 providing contacts composed of a shape memory
- 7 material;
- 8 providing contacts assembled in a compressed state
- 9 in a device for positioning the contacts;
- 10 positioning the device for positioning with the
- 11 contacts in the compressed state between the first
- and second electrical devices; and
- activating the contacts to a substantially
- uncompressed state to make the electrical connection
- between the first and second electrical devices;
- wherein the contacts are adapted to accommodate a
- variation in a gap width between the first and
- 18 second electrical devices
- 19 11. A method in accordance with Claim 10 wherein the
- 20 contacts are assembled into an interposer.
- 21 12. A method in accordance with Claim 11 wherein the
- 22 interposer comprises a land grid array.

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- 1 13. A method in accordance with Claim 10 wherein the
- 2 shape memory material is a nickel titanium alloy.
- 3 14. A contact for establishing an electrical connection
- 4 between a first electronic device and a second electronic
- 5 device, the contact comprising:
- a flexible conductive body formed in a first
- 7 position and adapted to be set into a second
- 8 position and activated into a third position in
- g order to accommodate a variable gap between the
- 10 first electronic device and the second electronic
- device for establishing the electrical connection.
- 12 15. A contact in accordance with Claim 14 wherein the
- 13 contact may be in compressed state, a second position,
- 14 and upon heat activation of a shape memory material, the
- 15 contact translates to a third position, being the
- 16 uncompressed state.
- 17 16. A contact in accordance with Claim 14 for use in an
- interposer wherein the shape memory material is a nickel
- 19 titanium alloy.
- 20 17. A contact in accordance with Claim 14 wherein the
- 21 shape memory material has a martinsitic transition
- 22 temperature in the range between -20 to 100 degrees C.
- 23 18. A contact in accordance with Claim 14 further
- 24 comprising the shape memory material being superelastic.

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- 1 19. A contact in accordance with Claim 14 wherein the
- 2 electrical contact is selected from the contacts having a
- 3 shape of an E, a C, a Random coil spring, and a helical
- 4 spring.